

Ordering number:ENN6079

PNP/NPN Silicon Epitaxial Planar Transistors



CPH3110/3210

DC/DC Converter Applications

Applications

- Relay drivers, lamp drivers, motor drivers, and strobes.

Features

- Adoption of MBIT processes.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Ultrasmall-sized package permitting applied sets to be made small and slim (0.9mm).
- High allowable power dissipation.

() : PNP

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		(-30)40	V
Collector-to-Emitter Voltage	V _{CEO}		(-30)	V
Emitter-to-Base Voltage	V _{EBO}		(-6)	V
Collector Current	I _C		(-5)	A
Collector Current (Pulse)	I _{CP}		(-7)	A
Base Current	I _B		(-1.2)	A
Collector Dissipation	P _C	Mounted on a ceramic board (600mm ² ×0.8mm)	0.9	W
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CB0}	V _{CB} =(-)30V, I _E =0			(-0.1)	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0			(-0.1)	μA
DC Current Gain	h _{FE}	V _{CE} =(-)2V, I _C =(-)500mA	200		560	
Gain-Bandwidth Product	f _T	V _{CE} =(-)10V, I _C =(-)500mA		(250)		MHz
				290		MHz
Output Capacitance	C _{ob}	V _{CB} =(-)10V, f=1MHz		(52)40		pF

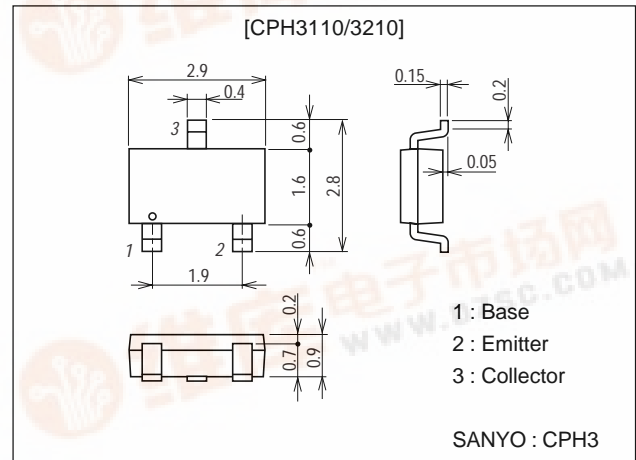
Marking : CPH3110 : AK, CPH3210 : CK

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Package Dimensions

unit:mm

2150A



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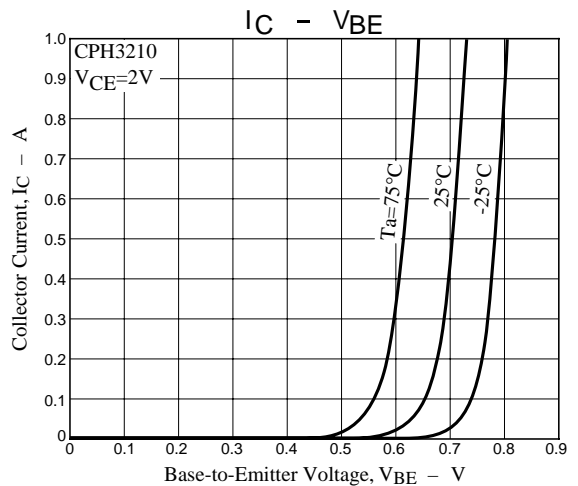
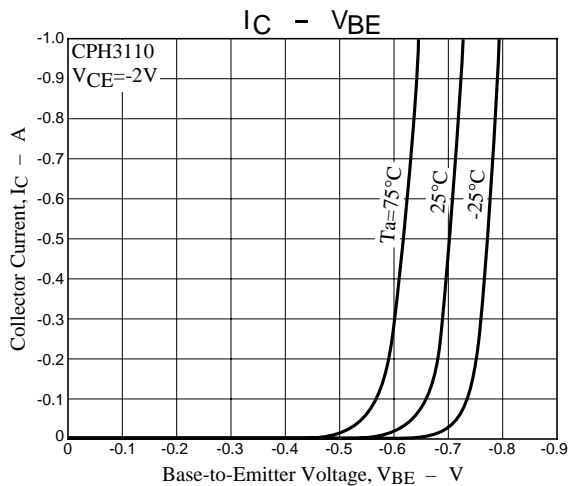
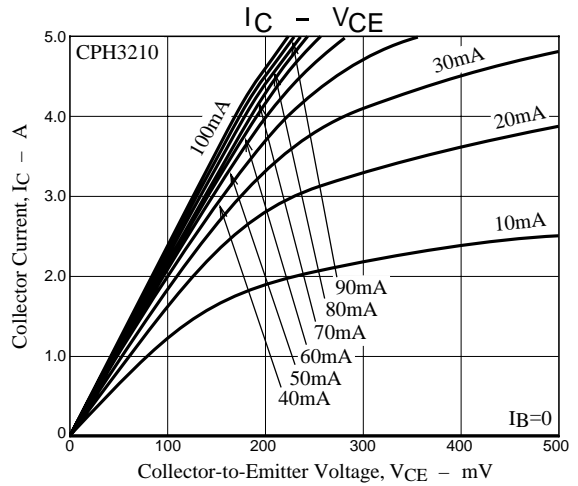
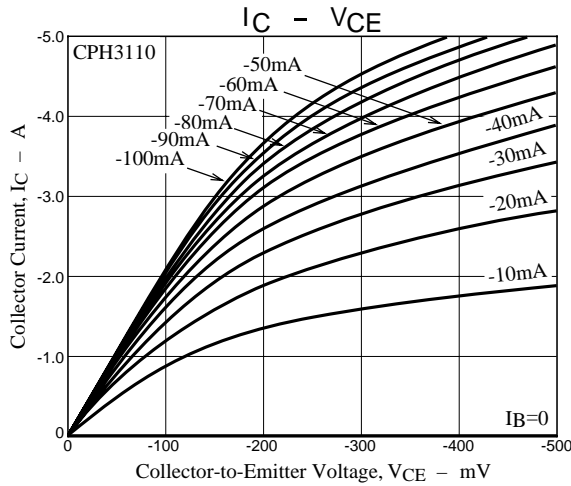
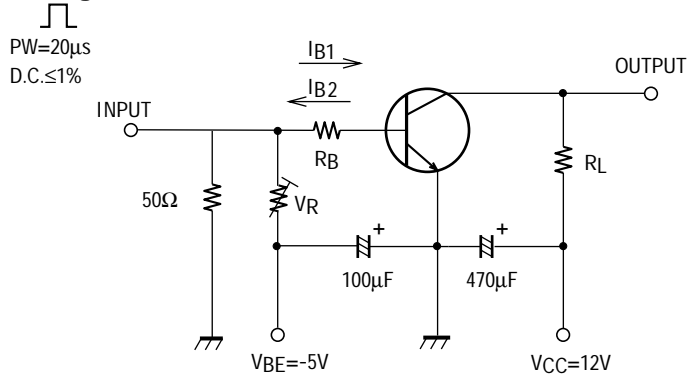


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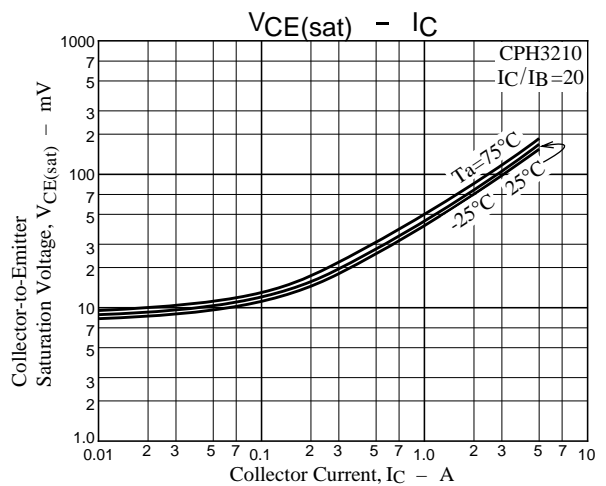
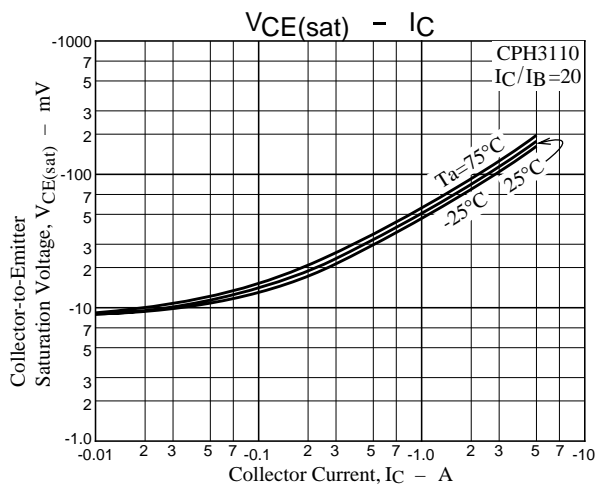
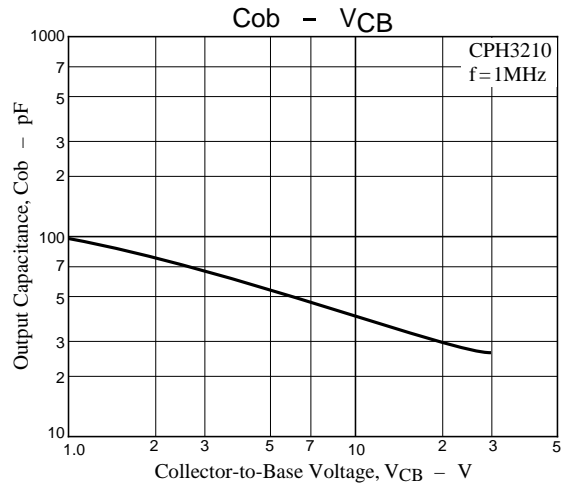
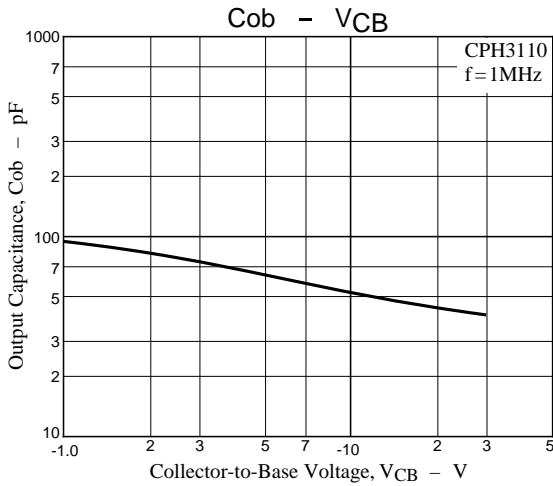
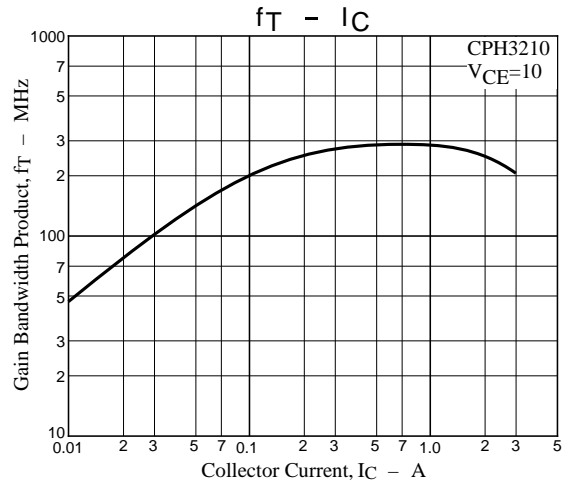
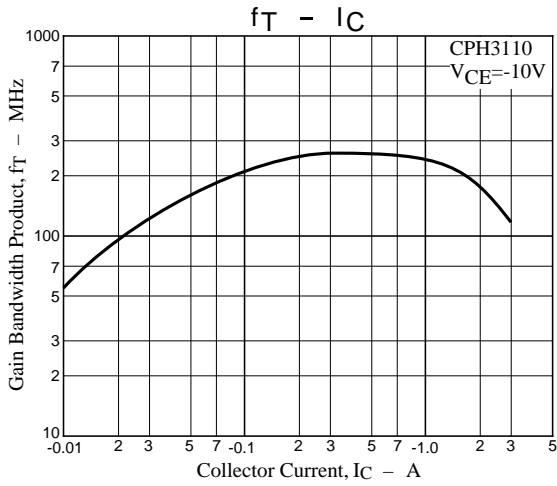
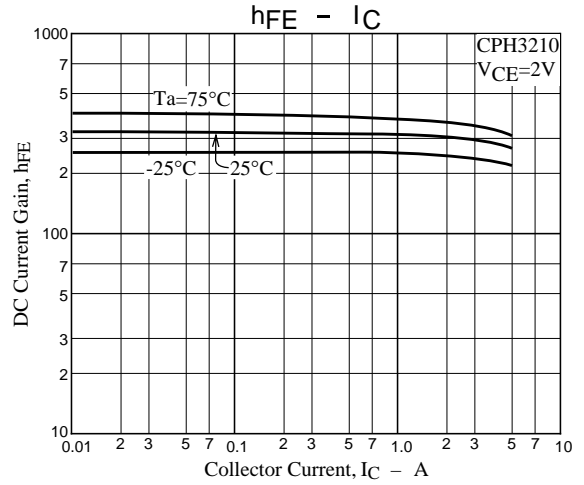
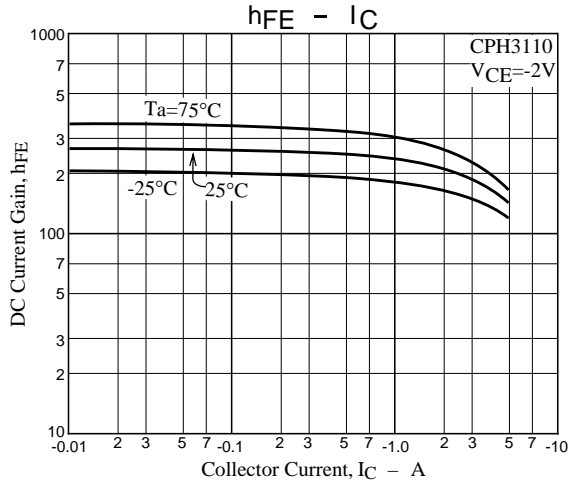
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)2.5A, I_B=(-)50mA$		(-140)	(-210)	mV
				110	165	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)2.5A, I_B=(-)50mA$		(-0.81)	(-1.2)	V
				0.82		V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-30)			V
			40			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-30)			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_C=(-)10\mu A, I_C=0$	(-6)			V
Turn-ON Time	t_{on}	See specified test circuit.		(30)30		ns
Storage Time	t_{stg}	See specified test circuit.		(190)		ns
				320		ns
Turn-OFF Time	t_f	See specified test circuit.		(17)14		ns

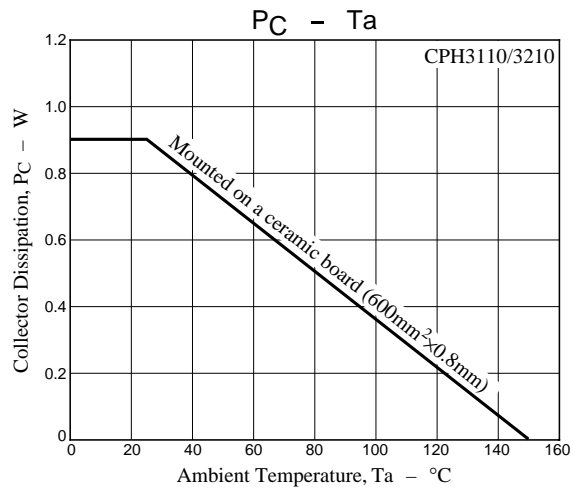
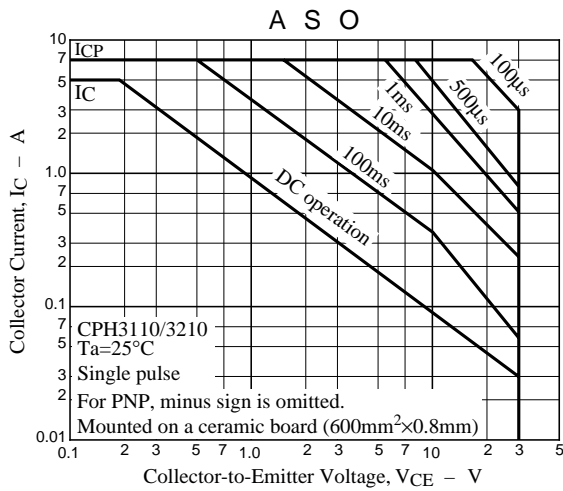
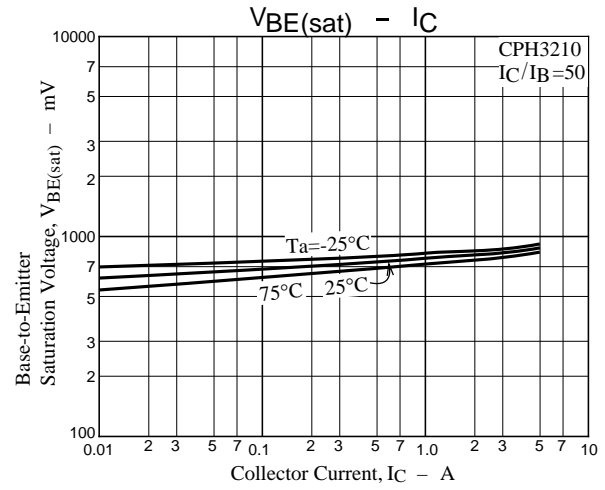
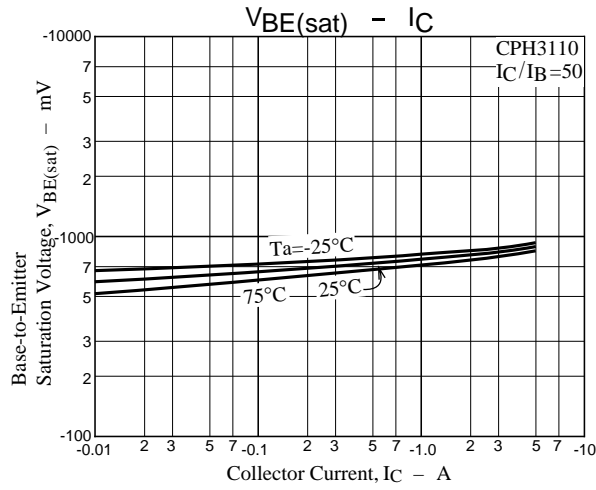
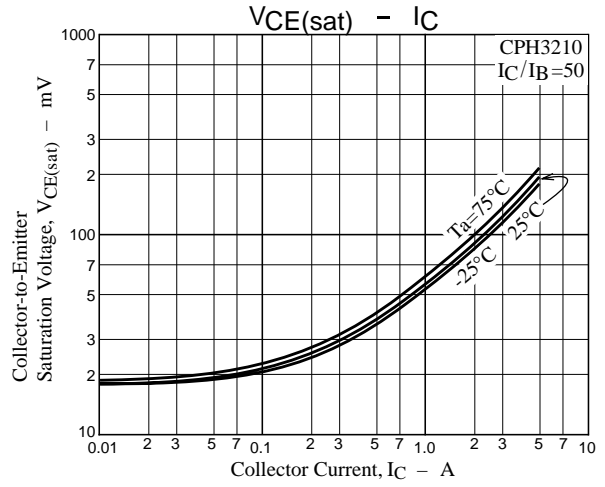
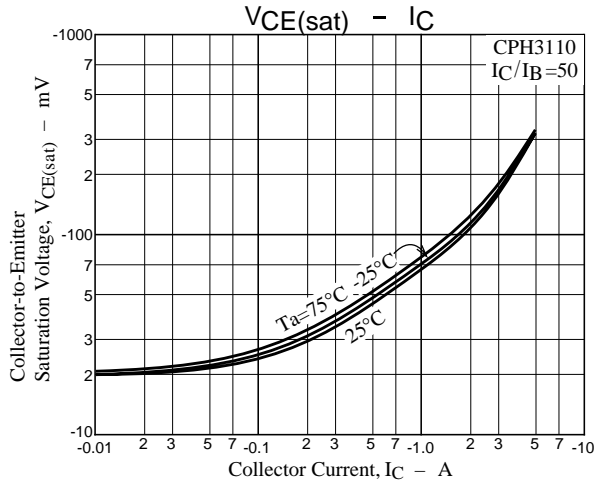
Switching Time Test Circuit



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